Data Sheet, Rev. 1.4, May 2017

TLE4209G

Automotive Power



Never stop thinking



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0.8A DC Motor Driver for Servo Driver Applications

TLE4209G



1 Overview

Features

- Optimized for manual headlight beam control applications
- Delivers up to 0.7 A continuous
- Low saturation voltage; typ.1.6 V total @ 25 °C; 0.7 A
- Output protected against short circuit
- Over temperature protection with hysteresis
- Over- and under voltage lockout
- Internal clamp diodes
- Enhanced SMD power package
- Green Product (RoHS compliant)
- AEC Qualified



PG-DSO-14

Description

The TLE4209G is a protected H-Bridge Driver designed specifically for automotive manual headlight beam control and industrial servo control applications with DC-brush motor loads.

The part is built using the bipolar high voltage power technology DOPL.

The standard enhanced power PG-DSO-14 package meets the application requirements and saves PCB-board space and costs. The package is lead- and halogen-free.

The servo-loop-parameter pos.- and neg. Hysteresis, pos.- and neg. deadband and angle-amplification are programmable with external resistors.

An internal window-comparator controls the input line. In the case of a fault condition, like short circuit to GND, short circuit to supply-voltage, and broken wire, the TLE4209G stops the motor immediately (brake condition).

Furthermore the built in features like over- and under voltage-lockout, short-circuit-protection and over-temperature-protection will open a wide range of automotive- and industrial applications.

Туре	Package	Marking
TLE4209G	PG-DSO-14	TLE4209G



Block Diagram

2 Block Diagram





Pin Configuration

3 Pin Configuration

3.1 Pin Assignment



Figure 2 Pin Configuration

3.2 Pin Definitions and Functions

Pin	Symbol	Function
1	FB	Feedback Input
2	HYST	Hysteresis I/O
3, 4, 5,	GND	Ground
10, 11,		
12		
6	OUT1	Power Output 1
7	NC	Not Connected
8	Vs	Power Supply Voltage
9	OUT2	Power Output 2
13	RANGE	Range Input
14	REF	Reference Input



4.1 Absolute Maximum Ratings

Absolute Maximum Ratings ¹⁾

 $T_j = -40 \cdot C$ to +150 ·C; all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Lin	Limit Values U		Conditions	
			Min.	Max.			
Voltage	es estatution esta estatution estatution est		4	H		1	
4.1.1	Supply voltage	Vs	-0.3	45	V	-	
4.1.2	Supply voltage	Vs	-1	-	V	<i>t</i> < 0.5 s; <i>I</i> _S > -2 A	
4.1.3	Logic input voltages (FB, REF, RANGE, HYST)	V ₁	-0.3	20	V	-	
Curren	ts	i			E		
4.1.4	Output current (OUT1, OUT2)	I _{OUT}	-	-	А	internally limited	
4.1.5	Output current (Diode)	I _{OUT}	-0.9	0.9	А	-	
4.1.6	Input current (FB, REF, RANGE, HYST)	I _{IN}	-2 -6	2 6	mA mA	<i>t</i> < 2 ms; <i>t</i> /T < 0.1	
Tempe	ratures	1			I		
4.1.7	Junction temperature	$T_{\rm j}$	-40	150	°C	-	
4.1.8	Storage temperature	T _{stg}	-50	150	°C	-	
		-			U		

1) Not subject to production test, specified by design.

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

4.2 Operating Range

Pos.	Parameter Symbol Limit Values		nit Values Unit		Conditions	
			Min.	Max.		
4.2.1	Supply voltage	V _S	8	18	V	After $V_{\rm S}$ rising above $V_{\rm UV \ ON}$
4.2.2	Supply voltage increasing	Vs	-0.3	V _{UV ON}	V	Outputs in tristate
4.2.3	Supply voltage decreasing	Vs	-0.3	V _{UV OFF}	V	Outputs in tristate
4.2.4	Output current	<i>I</i> _{OUT1-2}	-0.7	0.7	А	-
4.2.5	Input current (FB, REF)	I _{IN}	-50	500	μA	_
4.2.6	Junction temperature	Tj	-40	150	°C	-

Note: Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.



4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

Pos.	Parameter	Symbol		Limit Val	ues	Unit	Conditions	
			Min.	Тур.	Max.			
4.3.1	Junction to Soldeering Point ¹⁾	R_{thJSP}	-	-	25	K/W	measured to pin 5	
4.3.2	Junction to Ambient ¹⁾ minimal-footprint	R _{thJA}	-	130	-	K/W	2)	
4.3.3	Junction to Ambient ¹⁾ additional 600 mm ² CU area	R _{thJA}	-	65	-	K/W	3)	

1) Not subject to production test, specified by design.

2) JESD 51-2, 51-3, FR4 76.2 mm \times 114.3 mm \times 1.5 mm, 70 μm Cu, minimal footprint

3) JESD 51-2, 51-3, FR4 76.2 mm \times 114.3 mm \times 1.5 mm, 70 μm Cu, 600 mm 2 CU cooling area connected to Pins: 3, 4, 5, 10, 11, 12

4.4 Electrical Characteristics

Electrical Characteristics

 $V_{\rm S}$ = 8 V to 18 V, $T_{\rm j}$ = -40 ·C to +150 ·C, $I_{\rm OUT1-2}$ = 0 A, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
Curren	t Consumption						
4.4.1	Supply current	Is	-	12	20	mA	-
4.4.2	Supply current	Is	-	20	30	mA	$I_{OUT1} = 0.3 \text{ A}$ $I_{OUT2} = -0.3 \text{ A}$
4.4.3	Supply current	I _S	-	30	50	mA	I _{OUT1} = 0.7 A I _{OUT2} = -0.7 A
Over- a	nd Under Voltage Lockout						
4.4.4	UV Switch ON voltage	$V_{\rm UV ON}$	-	7.4	8	V	$V_{\rm S}$ increasing
4.4.5	UV Switch OFF voltage	$V_{\rm UV OFF}$	6.3	6.9	_	V	$V_{\rm S}$ decreasing
4.4.6	UV ON/OFF Hysteresis	$V_{\rm UVHY}$	-	0.5	_	V	V _{UV ON} - V _{UV OFF}
4.4.7	OV Switch OFF voltage	$V_{\rm OVOFF}$	-	20.5	23	V	$V_{\rm S}$ increasing
4.4.8	OV Switch ON voltage	V _{OV ON}	17.5	20	_	V	$V_{\rm S}$ decreasing
4.4.9	OV ON/OFF Hysteresis	V _{OVHY}	-	0.5	-	V	V _{OV OFF} - V _{OV ON}
Output	s OUT1-2, Saturation Voltag		-		<u>.</u>		+
4.4.10	Source (upper) I_{OUT} = -0.3 A	V _{SAT U}	-	0.90	1.20	V	<i>T</i> _j = 25 °C
4.4.11	Sink (upper) I _{OUT} = -0.7 A	V _{SAT U}	-	1.10	1.50	V	<i>T</i> _j = 25 °C
4.4.12	Sink (lower) I _{OUT} = 0.3 A	V _{SAT L}	-	0.25	0.40	V	<i>T</i> _j = 25 °C
4.4.13	Sink (lower) I _{OUT} = 0.7 A	V _{SAT L}	-	0.45	0.75	V	<i>T</i> _j = 25 °C



Electrical Characteristics (cont'd)

 $V_{\rm S}$ = 8 V to 18 V, $T_{\rm j}$ = -40 ·C to +150 ·C, $I_{\rm OUT1-2}$ = 0 A, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions	
			Min.	Тур.	Max.			
4.4.14	Total drop $I_{OUT} = 0.3 \text{ A}$	V _{SAT}	-	1.2	1.7	V	$V_{\text{SAT}} = V_{\text{SAT U}} + V_{\text{SAT L}}$	
4.4.15	Total drop $I_{OUT} = 0.7 \text{ A}$	V _{SAT}	-	1.6	2.5	V	$V_{\text{SAT}} = V_{\text{SAT U}} + V_{\text{SAT L}}$	
Output	s OUT1-2, Clamp Diodes	I	_1	I				
4.4.16	Forward voltage; upper	$V_{\rm FU}$	-	1	1.5	V	<i>I</i> _F = 0.3 A	
4.4.17	Upper leakage current	$I_{\rm LKU}$	-	_	5	mA	<i>I</i> _F = 0.3 A	
4.4.18	Forward voltage; lower	V _{FL}	-	0.9	1.4	V	<i>I</i> _F = 0.3 A	
Input-Ir	nterface, Input REF		-		I			
4.4.19	Quiescent voltage	V_{REFq}	-	200	-	mV	<i>I</i> _{REF} = 0 μA	
4.4.20	Input resistance	R _{REF}	_	6	_	kΩ	0 V < V _{REF} < 0.5 V	
Input-Ir	nterface, Input FB	I	_1	I				
4.4.21	Quiescent voltage	V_{FBq}	-	200	_	mV	I _{FB} = 0 μA	
4.4.22	Input resistance	R _{FB}	-	6	-	kΩ	0 V < V _{FB} < 0.5 V	
Input-Ir	nterface, Input/Output HYST		-		I	1		
4.4.23	Current Amplification $A_{\text{HYST}} = I_{\text{HYST}} / (I_{\text{REF}} - I_{\text{FB}})$	A _{HYST}	0.8	0.95	1.1	_	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	
4.4.24	Current Offset	I _{HYSTIO}	-2	0.35	3	μA	$I_{\text{REF}} = I_{\text{FB}} = 250 \ \mu\text{A};$ $V_{\text{HYST}} = V_{\text{S}} / 2$	
4.4.25	Threshold voltage High	V _{HYH} / V _S	-	52	-	%	-	
4.4.26	Deadband voltage High	V _{DBH} / V _S	-	50.4	-	%	-	
4.4.27	Deadband voltage Low	$V_{\rm DBL}$ / $V_{\rm S}$	-	49.6	-	%	-	
4.4.28	Threshold voltage Low	$V_{\rm HYL}$ / $V_{\rm S}$	-	48	-	%	-	
4.4.29	Hysteresis Window	V _{HYW} / V _S	3	4	5	%	$(V_{\rm HYH}$ - $V_{\rm HYL})$ / $V_{\rm S}$	
4.4.30	Deadband Window	V _{DBW} / V _S	0.4	0.8	1.2	%	$(V_{\rm DBH}$ - $V_{\rm DBL})$ / $V_{\rm S}$	
Input-Ir	nterface, Input RANGE							
4.4.31	Input current	I_{RANGE}	-1	-	1	μA	$0 V < V_{RANGE} < V_{S}$	
4.4.32	Switch-OFF voltage High	V_{OFFH}	-25	0	100	mV	refer to V _S	
4.4.33	Switch-OFF voltage Low	VOFFL	300	400	500	mV	refer to GND	



Electrical Characteristics (cont'd)

 $V_{\rm S}$ = 8 V to 18 V, $T_{\rm j}$ = -40 ·C to +150 ·C, $I_{\rm OUT1-2}$ = 0 A, all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Pos.	Parameter	Symbol		Limit Val	Unit	Conditions	
			Min.	Тур.	Max.		
Therma	al Shutdown	1	1	1	L		
4.4.34	Thermal shutdown junction temperature ¹⁾	$T_{\rm jSD}$	150	175	200	°C	-
4.4.35	Thermal switch-on junction temperature ¹⁾	T _{jSO}	120	-	170	°C	-
4.4.36	Temperature hysteresis	ΔT	_	30	_	К	-

1) Not subject to production test, specified by design.



TLE4209G

Application Information



5 Application Information

Figure 3 Application Diagram

Note: In the application the PIN 7 can remain not connected.





Application Information



Figure 4 Hysteresis, Phaselag and Deadband-Definitions



TLE4209G

Application Information





Package Outlines

6 Package Outlines



Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": http://www.infineon.com/products.



7 Revision History

Revision	Date	Changes
1.1	2007-04-11	RoHS-compliant DSO package version of the TLE 4209
		All pages: Infineon logo updated
		Page 1:
		"AEC qualified" and "RoHS" logo added, "Green Product (RoHS compliant)" and
		"AEC qualified" statement added to feature list, package names changed to
		RoHS compliant versions, package pictures updated
		Page 13:
		Package names changed to RoHS compliant versions, "Green Product" description added
		Revision History added
		Legal Disclaimer added
1.2	2007-08-10	Package name changed to PG-DSO-14-22
1.3	2008-02-04	Page 1: Editorial change: deleted "fully" (The term "fully protected" often leads to misunderstandings as it is unclear with respect to which parameters).
1.4	2017-05-19	Package suffix deleted

Edition 2017-05-19

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